



Vincotech

B0-SL10NIB600S701-PA29F48Z
B0-SL10NIC600S701-PA39F48Z
datasheet

flowNPC S3 split

950 V / 600 A

Topology features

- Kelvin Emitter for improved switching performance
- Temperature sensor
- Neutral Point Clamped Topology (I-Type)
- Split topology

Component features

- Low collector emitter saturation voltage
- High speed and smooth switching

Housing features

- Base isolation: AlN
- CTI600 housing material
- Compact, baseplate-less housing
- VINcoPress Technology
- Thermo-mechanical push-and-pull force relief
- Press-fit pin
- Reliable cold welding connection

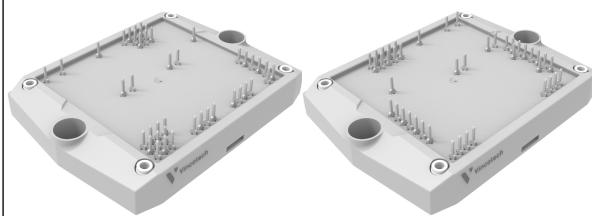
Target applications

- Solar Inverters

Types

- B0-SL10NIB600S701-PA29F48Z
- B0-SL10NIC600S701-PA39F48Z

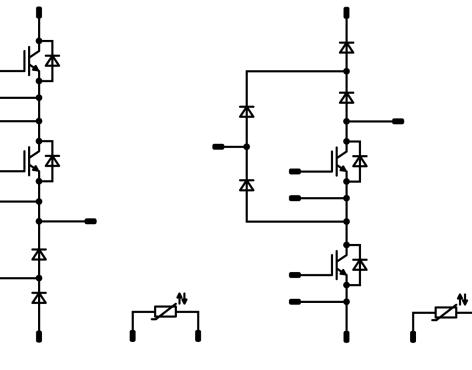
flow S3 12 mm housing



PA29F48Z

PA39F48Z

Schematic



PA29F48Z

PA39F48Z



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Maximum Ratings

$T_j = 25^\circ\text{C}$, unless otherwise specified

Parameter	Symbol	Conditions	Value	Unit
Buck Switch				
Collector-emitter voltage	V_{CES}		950	V
Collector current (DC current)	I_C	$T_j = T_{jmax}$ $T_s = 80^\circ\text{C}$	444	A
Repetitive peak collector current	I_{CRM}	t_p limited by T_{jmax}	1200	A
Total power dissipation	P_{tot}	$T_j = T_{jmax}$ $T_s = 80^\circ\text{C}$	864	W
Gate-emitter voltage	V_{GES}		± 20	V
Maximum junction temperature	T_{jmax}		175	$^\circ\text{C}$

Buck Diode

Peak repetitive reverse voltage	V_{RRM}		1200	V
Forward current (DC current)	I_F	$T_j = T_{jmax}$ $T_s = 80^\circ\text{C}$	171	A
Repetitive peak forward current	I_{FRM}	t_p limited by T_{jmax}	728	A
Surge (non-repetitive) forward current	I_{FSM}	Single Half Sine Wave, $t_p = 10 \text{ ms}$ $T_j = 25^\circ\text{C}$	1040	A
Total power dissipation	P_{tot}	$T_j = T_{jmax}$ $T_s = 80^\circ\text{C}$	432	W
Maximum junction temperature	T_{jmax}		175	$^\circ\text{C}$

Buck Sw. Protection Diode

Peak repetitive reverse voltage	V_{RRM}		950	V
Forward current (DC current)	I_F	$T_j = T_{jmax}$ $T_s = 80^\circ\text{C}$	77	A
Repetitive peak forward current	I_{FRM}	t_p limited by T_{jmax}	200	A
Total power dissipation	P_{tot}	$T_j = T_{jmax}$ $T_s = 80^\circ\text{C}$	160	W
Maximum junction temperature	T_{jmax}		175	$^\circ\text{C}$



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Maximum Ratings

$T_j = 25^\circ\text{C}$, unless otherwise specified

Parameter	Symbol	Conditions	Value	Unit
Boost Switch				
Collector-emitter voltage	V_{CES}		950	V
Collector current (DC current)	I_C	$T_j = T_{jmax}$ $T_s = 80^\circ\text{C}$	602	A
Repetitive peak collector current	I_{CRM}	t_p limited by T_{jmax}	1200	A
Total power dissipation	P_{tot}	$T_j = T_{jmax}$ $T_s = 80^\circ\text{C}$	750	W
Gate-emitter voltage	V_{GES}		± 20	V
Maximum junction temperature	T_{jmax}		175	$^\circ\text{C}$

Boost Diode

Peak repetitive reverse voltage	V_{RRM}		950	V
Forward current (DC current)	I_F	$T_j = T_{jmax}$ $T_s = 80^\circ\text{C}$	209	A
Repetitive peak forward current	I_{FRM}	t_p limited by T_{jmax}	600	A
Total power dissipation	P_{tot}	$T_j = T_{jmax}$ $T_s = 80^\circ\text{C}$	413	W
Maximum junction temperature	T_{jmax}		175	$^\circ\text{C}$

Boost Sw. Inv. Diode

Peak repetitive reverse voltage	V_{RRM}		950	V
Forward current (DC current)	I_F	$T_j = T_{jmax}$ $T_s = 80^\circ\text{C}$	209	A
Repetitive peak forward current	I_{FRM}	t_p limited by T_{jmax}	600	A
Total power dissipation	P_{tot}	$T_j = T_{jmax}$ $T_s = 80^\circ\text{C}$	413	W
Maximum junction temperature	T_{jmax}		175	$^\circ\text{C}$



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Maximum Ratings

$T_j = 25^\circ\text{C}$, unless otherwise specified

Parameter	Symbol	Conditions	Value	Unit
Boost Sw. Protection Diode				
Peak repetitive reverse voltage	V_{RRM}		950	V
Forward current (DC current)	I_F	$T_j = T_{jmax}$	77	A
Repetitive peak forward current	I_{FRM}	t_p limited by T_{jmax}	200	A
Total power dissipation	P_{tot}	$T_j = T_{jmax}$	160	W
Maximum junction temperature	T_{jmax}		175	$^\circ\text{C}$

Boost D. Protection Diode

Peak repetitive reverse voltage	V_{RRM}		950	V
Forward current (DC current)	I_F	$T_j = T_{jmax}$	77	A
Repetitive peak forward current	I_{FRM}	t_p limited by T_{jmax}	200	A
Total power dissipation	P_{tot}	$T_j = T_{jmax}$	160	W
Maximum junction temperature	T_{jmax}		175	$^\circ\text{C}$

Module Properties

Thermal Properties				
Storage temperature	T_{stg}		-40...+125	$^\circ\text{C}$
Operation temperature under switching condition	T_{jop}		-40...+($T_{jmax} - 25$)	$^\circ\text{C}$

Isolation Properties

Isolation voltage	V_{isol}	DC Test Voltage* $t_p = 2\text{ s}$	6000	V
Creepage distance		B0-SL10NIB600S701-PA29F48Z B0-SL10NIC600S701-PA39F48Z	>12,7 9,93	mm
Clearance		B0-SL10NIB600S701-PA29F48Z B0-SL10NIC600S701-PA39F48Z	11,58 8,06	mm
Comparative Tracking Index	CTI		≥ 600	

*100 % tested in production



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Characteristic Values

Parameter	Symbol	Conditions					Values			Unit
		V_{GE} [V]	V_{GS} [V]	V_{CE} [V]	V_{DS} [V]	I_C [A]	T_j [°C]	Min	Typ	

Buck Switch

Static

Gate-emitter threshold voltage	$V_{GE(\text{th})}$	$V_{CE} = V_{GE}$			0,00975	25	4,35	5,1	5,85	V
Collector-emitter saturation voltage	$V_{CE(\text{sat})}$		15		600	25 125 150		1,82 2,07 2,13	2,25 ⁽¹⁾	V
Collector-emitter cut-off current	I_{CES}		0	950		25			12	µA
Gate-emitter leakage current	I_{GES}		20	0		25			300	nA
Internal gate resistance	r_g							0,5		Ω
Input capacitance	C_{res}	$f = 100 \text{ kHz}$	0	25	25	25	37800		pF	
Output capacitance	C_{oes}									
Reverse transfer capacitance	C_{res}									
Gate charge	Q_g		±15		0	25		1350		nC

Thermal

Thermal resistance junction to sink ⁽²⁾	$R_{th(j-s)}$	$\lambda_{\text{paste}} = 5,2 \text{ W/mK}$ (PTM)						0,11		K/W
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Dynamic

Turn-on delay time	$t_{d(on)}$	$R_{gon} = 2 \Omega$ $R_{goff} = 4 \Omega$	±15	600	355	25		211,78		
Rise time	t_r					125		215,26		ns
						150		216,47		
Turn-off delay time	$t_{d(off)}$					25		34,5		
						125		37,3		
Fall time	t_f					150		37,75		ns
Turn-on energy (per pulse)	E_{on}	$Q_{tFWD}=0,835 \mu\text{C}$ $Q_{fFWD}=0,851 \mu\text{C}$ $Q_{ffwd}=0,855 \mu\text{C}$				25		270,24		
						125		311,24		
Turn-off energy (per pulse)	E_{off}					150		321,97		ns
						25		29,46		
						125		45,96		
						150		56,5		
						25		9,16		
						125		10,02		mWs
						150		9,98		
						25		11,55		
						125		17,35		
						150		19,23		mWs



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Characteristic Values

Parameter	Symbol	Conditions						Values			Unit
		V_{GE} [V]	V_{GS} [V]	V_{CE} [V]	V_{DS} [V]	I_C [A]	I_D [A]	T_j [°C]	Min	Typ	Max

Buck Diode

Static

Forward voltage	V_F				160	25 125 150		1,72 2,17 2,32	1,8 ⁽¹⁾	V
Reverse leakage current	I_R	$V_r = 1200$ V			25		280	1600	μ A	

Thermal

Thermal resistance junction to sink ⁽²⁾	$R_{th(j-s)}$	$\lambda_{paste} = 5,2$ W/mK (PTM)						0,22		K/W
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Dynamic

Peak recovery current	I_{RM}	$di/dt=9122$ A/ μ s $di/dt=6238$ A/ μ s $di/dt=6469$ A/ μ s	± 15	600	355	25		61,78		
Reverse recovery time	t_{rr}					125		62,06		
Recovered charge	Q_r					150		62,93		
Reverse recovered energy	E_{rec}		± 15	600	355	25		22,52		
Peak rate of fall of recovery current	$(di_{rr}/dt)_{max}$					125		22,77		
						150		23,05		ns
			± 15	600	355	25		0,835		
						125		0,851		μ C
						150		0,855		
			± 15	600	355	25		0,26		
						125		0,263		mWs
						150		0,266		
			± 15	600	355	25		6756,77		
						125		7049,49		
						150		6408,11		A/ μ s



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Characteristic Values

Parameter	Symbol	Conditions						Values			Unit
		V_{GE} [V]	V_{GS} [V]	V_{CE} [V]	V_{DS} [V]	I_C [A]	I_D [A]	T_j [°C]	Min	Typ	Max

Buck Sw. Protection Diode

Static

Forward voltage	V_F				100	25 125 150	2,1	2,64 2,44 2,36	2,8 ⁽¹⁾	V
Reverse leakage current	I_R	$V_r = 950$ V			25				4	µA

Thermal

Thermal resistance junction to sink ⁽²⁾	$R_{th(j-s)}$	$\lambda_{paste} = 5,2$ W/mK (PTM)						0,59		K/W
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Characteristic Values

Parameter	Symbol	Conditions						Values			Unit
		V_{GE} [V]	V_{GS} [V]	V_{CE} [V]	V_{DS} [V]	I_C [A]	I_D [A]	T_j [°C]	Min	Typ	

Boost Switch

Static

Gate-emitter threshold voltage	$V_{GE(th)}$	$V_{CE} = V_{GE}$			0,00975	25	4,15	4,85	5,65	V
Collector-emitter saturation voltage	$V_{CE(sat)}$		15		600	25 125 150		1,21 1,23 1,24	1,4 ⁽¹⁾	V
Collector-emitter cut-off current	I_{CES}		0	950		25			12	µA
Gate-emitter leakage current	I_{GES}		20	0		25			300	nA
Internal gate resistance	r_g							0,5		Ω
Input capacitance	C_{res}	$f = 100$ kHz	0	25	25	25	73800	795	330	pF
Output capacitance	C_{oes}									
Reverse transfer capacitance	C_{res}									
Gate charge	Q_g		±15		0	25		6150		nC

Thermal

Thermal resistance junction to sink ⁽²⁾	$R_{th(j-s)}$	$\lambda_{paste} = 5,2$ W/mK (PTM)						0,13		K/W
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Dynamic

Turn-on delay time	$t_{d(on)}$	$R_{gon} = 2 \Omega$ $R_{goff} = 2 \Omega$	±15	600	600	25		488,96			ns
Rise time	t_r					125		493,44			
						150		498,24			
Turn-off delay time	$t_{d(off)}$					25		50,24			
						125		54,4			
Fall time	t_f					150		56			
Turn-on energy (per pulse)	E_{on}	$Q_{fFWD}=10,1$ µC $Q_{rfFWD}=24$ µC $Q_{ffFWD}=29,02$ µC				25		395,52			
						125		447,68			
						150		460,8			
Turn-off energy (per pulse)	E_{off}					25		250,52			
						125		341,62			
						150		358,11			
						25		23,23			
						125		27,36			
						150		29,06			mWs
						25		78,24			
						125		106,17			
						150		113,82			mWs



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Characteristic Values

Parameter	Symbol	Conditions						Values			Unit
		V_{GE} [V]	V_{GS} [V]	V_{CE} [V]	V_{DS} [V]	I_C [A]	I_D [A]	T_j [°C]	Min	Typ	Max

Boost Diode

Static

Forward voltage	V_F				300	25 125 150	2,1	2,59 2,43 2,37	2,8 ⁽¹⁾	V
Reverse leakage current	I_R	$V_r = 950$ V			25			12	μ A	

Thermal

Thermal resistance junction to sink ⁽²⁾	$R_{th(j-s)}$	$\lambda_{paste} = 5,2$ W/mK (PTM)						0,23		K/W
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Dynamic

Peak recovery current	I_{RM}	$di/dt=10313$ A/ μ s $di/dt=9888$ A/ μ s $di/dt=9489$ A/ μ s	± 15	600	600	25		195,57			A
Reverse recovery time	t_{rr}					125		279,82			
Recovered charge	Q_r					150		299,08			
Reverse recovered energy	E_{rec}		± 15	600	600	25		145,91			ns
Peak rate of fall of recovery current	$(di_{rr}/dt)_{max}$					125		218,84			
						150		244,17			
			± 15	600	600	25		10,1			μ C
						125		24			
						150		29,02			
			± 15	600	600	25		2,99			mWs
						125		8,09			
						150		9,95			
			± 15	600	600	25		8181			A/ μ s
						125		4351			
						150		4085			



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Characteristic Values

Parameter	Symbol	Conditions						Values			Unit
		V_{GE} [V]	V_{GS} [V]	V_{CE} [V]	V_{DS} [V]	I_C [A]	I_D [A]	T_j [°C]	Min	Typ	

Boost Sw. Inv. Diode

Static

Forward voltage	V_F				300	25 125 150	2,1	2,59 2,43 2,37	2,8 ⁽¹⁾	V
Reverse leakage current	I_R	$V_r = 950$ V			25				12	µA

Thermal

Thermal resistance junction to sink ⁽²⁾	$R_{th(j-s)}$	$\lambda_{paste} = 5,2$ W/mK (PTM)						0,23		K/W
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Boost Sw. Protection Diode

Static

Forward voltage	V_F				100	25 125 150	2,1	2,64 2,44 2,36	2,8 ⁽¹⁾	V
Reverse leakage current	I_R	$V_r = 950$ V			25				4	µA

Thermal

Thermal resistance junction to sink ⁽²⁾	$R_{th(j-s)}$	$\lambda_{paste} = 5,2$ W/mK (PTM)						0,59		K/W
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Boost D. Protection Diode

Static

Forward voltage	V_F				100	25 125 150	2,1	2,64 2,44 2,36	2,8 ⁽¹⁾	V
Reverse leakage current	I_R	$V_r = 950$ V			25				4	µA

Thermal

Thermal resistance junction to sink ⁽²⁾	$R_{th(j-s)}$	$\lambda_{paste} = 5,2$ W/mK (PTM)						0,59		K/W
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Characteristic Values

Parameter	Symbol	Conditions					Values			Unit
		V_{GE} [V]	V_{GS} [V]	V_{CE} [V]	V_{DS} [V]	I_C [A]	T_j [°C]	Min	Typ	Max

Thermistor

Static

Rated resistance	R					25		22		kΩ
Deviation of R100	$A_{R/R}$	$R_{100} = 1484 \Omega$				100	-5		5	%
Power dissipation	P					25		130		mW
Power dissipation constant	d					25		1,5		mW/K
B-value	$B_{(25/50)}$	Tol. ±1 %						3962		K
B-value	$B_{(25/100)}$	Tol. ±1 %						4000		K
Vincotech Thermistor Reference									I	

(¹) Value at chip level

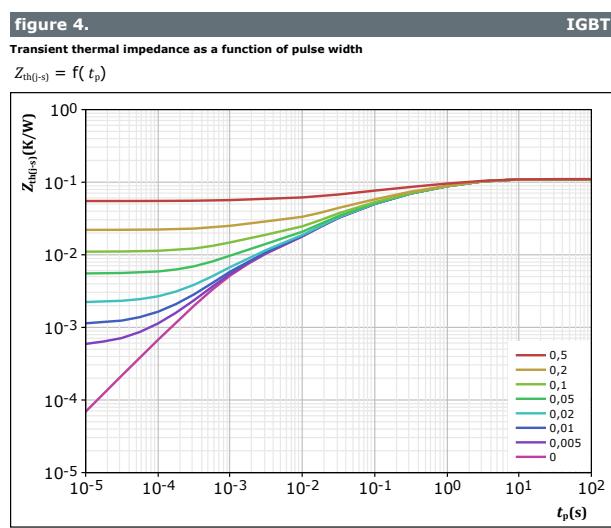
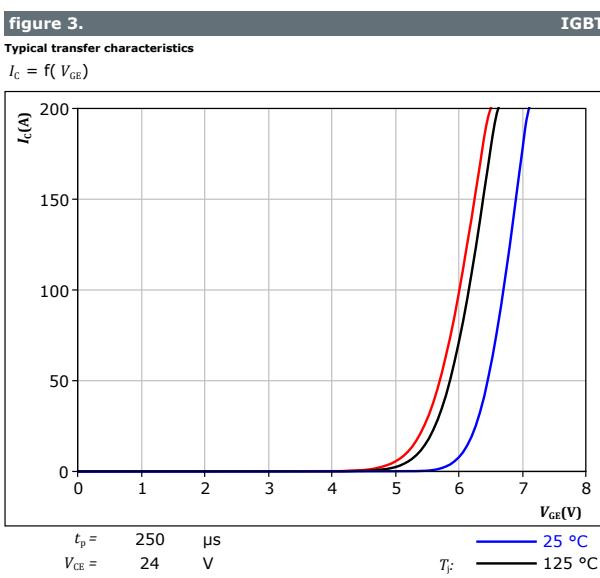
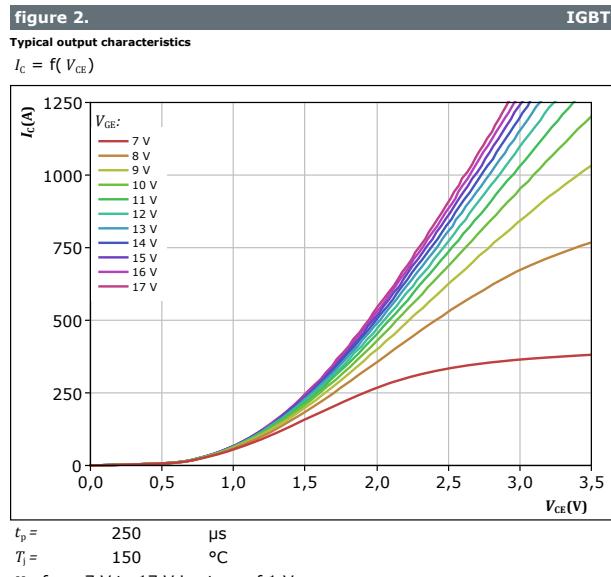
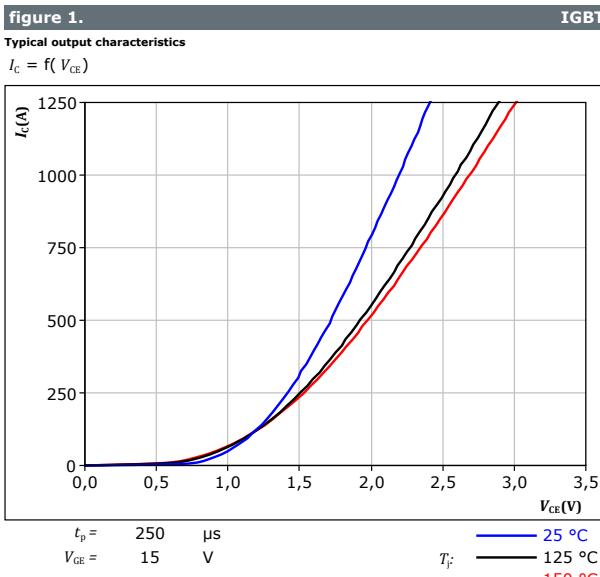
(²) Only valid with pre-applied Vincotech thermal interface material.



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Buck Switch Characteristics



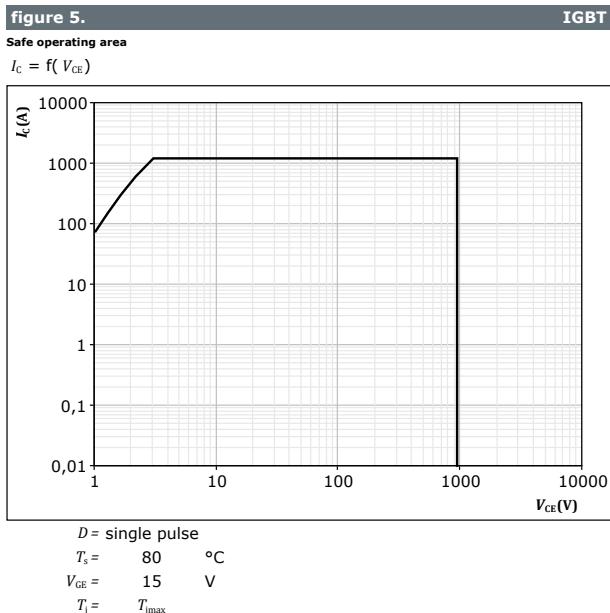
$D = t_p / T$	t_p / T	$R_{th(j-s)}$ (K/W)	τ (s)
		IGBT thermal model values	
R (K/W)			
1,72E-02		3,12E+00	
2,61E-02		9,92E-01	
3,34E-02		1,78E-01	
2,60E-02		2,52E-02	
7,27E-03		1,28E-03	



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Buck Switch Characteristics

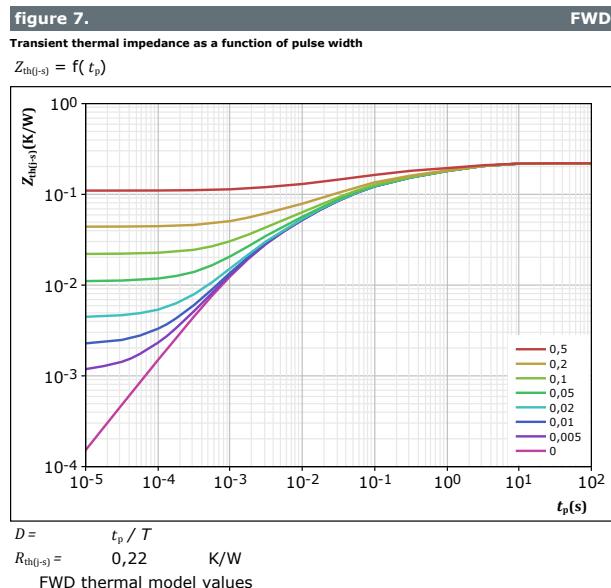
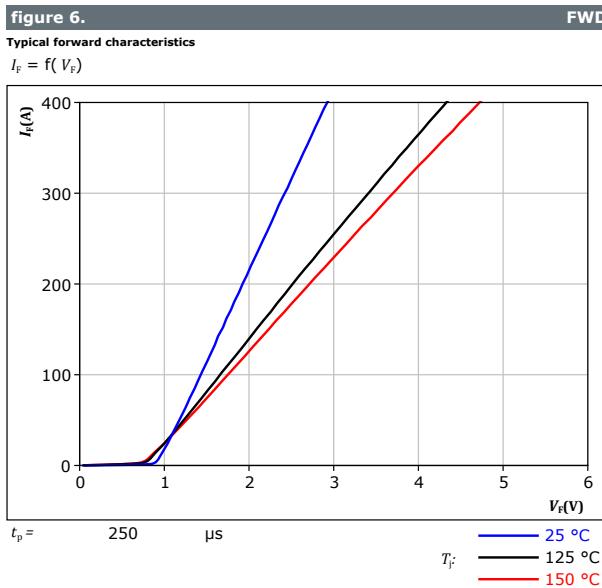




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Buck Diode Characteristics





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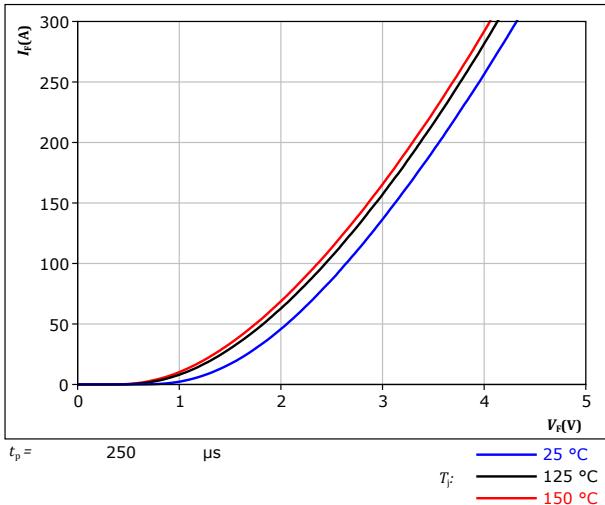
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Buck Sw. Protection Diode Characteristics

figure 8.

Typical forward characteristics

$$I_F = f(V_F)$$

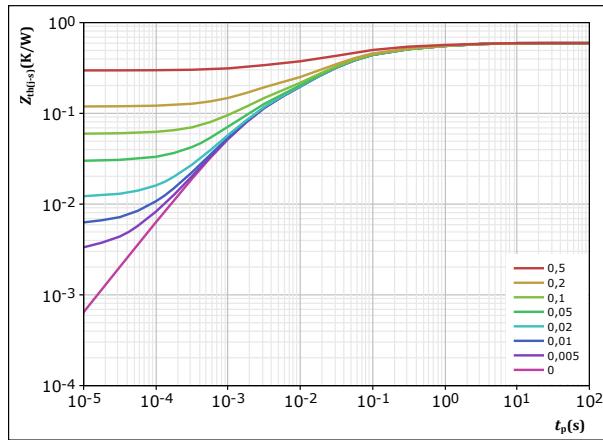


FWD

figure 9.

Transient thermal impedance as a function of pulse width

$$Z_{th(j-s)} = f(t_p)$$



FWD

$$D = \frac{t_p / T}{0,594} \quad K/W$$

FWD thermal model values

$R (K/W)$	$\tau (s)$
5,02E-02	2,46E+00
7,95E-02	4,43E-01
2,28E-01	5,90E-02
1,50E-01	1,50E-02
8,75E-02	1,73E-03



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Boost Switch Characteristics

figure 10. IGBT

Typical output characteristics

$$I_C = f(V_{CE})$$

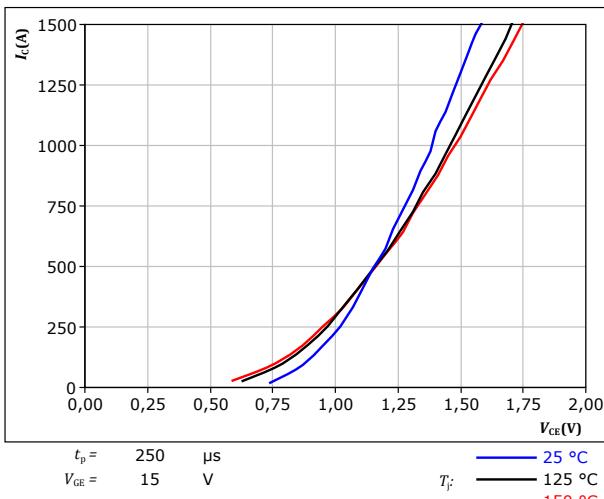


figure 11. IGBT

Typical output characteristics

$$I_C = f(V_{CE})$$

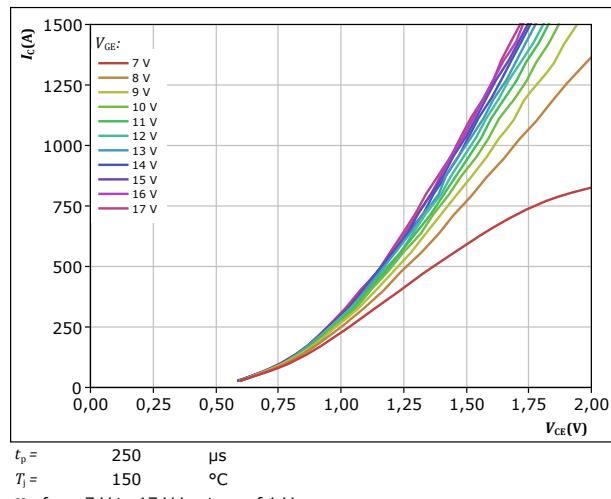


figure 12. IGBT

Typical transfer characteristics

$$I_C = f(V_{GE})$$

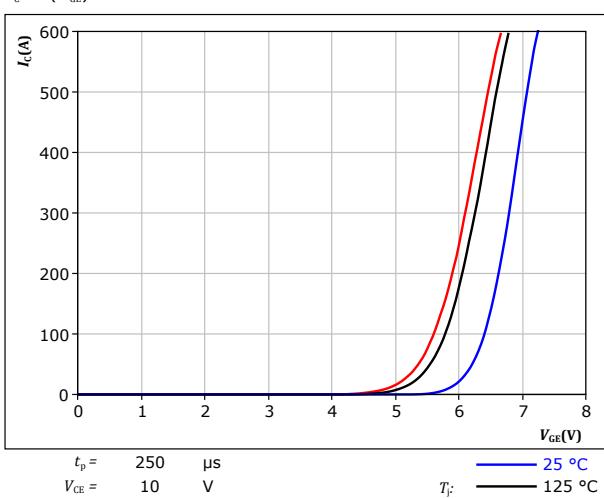
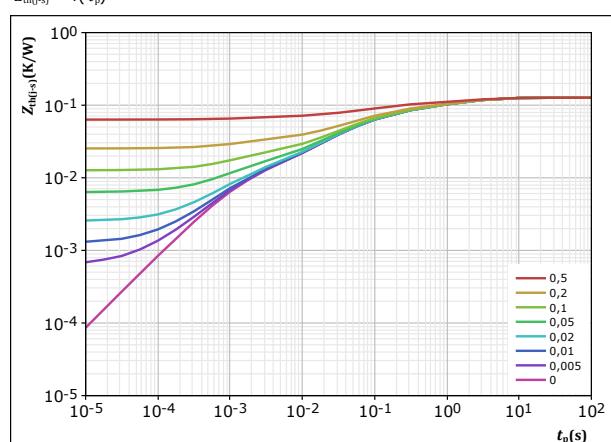


figure 13. IGBT

Transient thermal impedance as a function of pulse width

$$Z_{th(j-s)} = f(t_p)$$

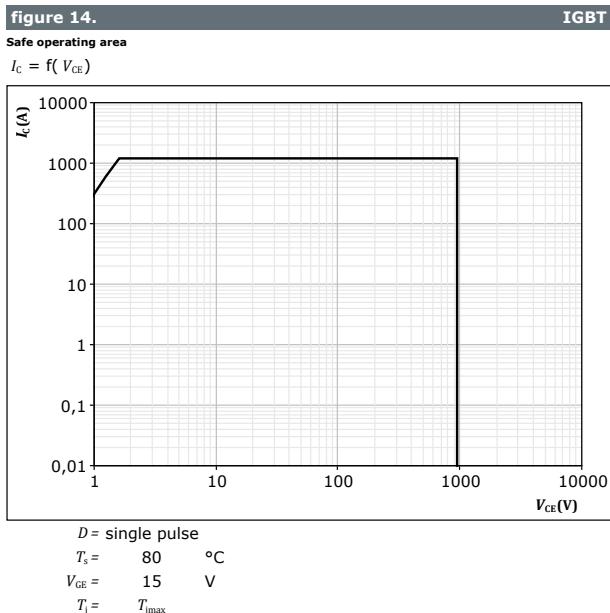




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Boost Switch Characteristics





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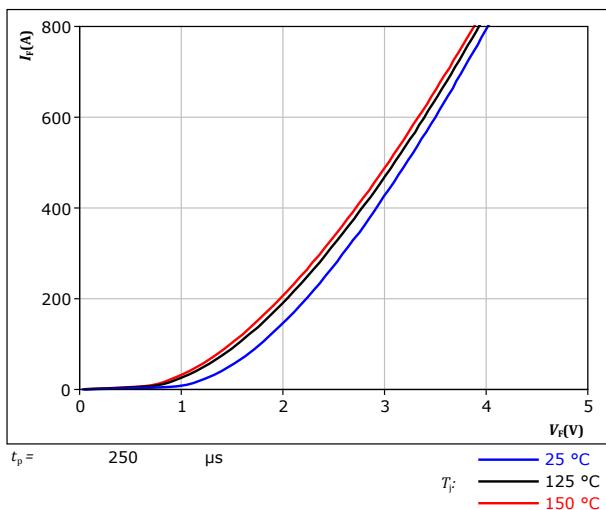
Boost Diode Characteristics

figure 15.

Typical forward characteristics

$$I_F = f(V_F)$$

FWD



$$t_p = 250 \mu\text{s}$$

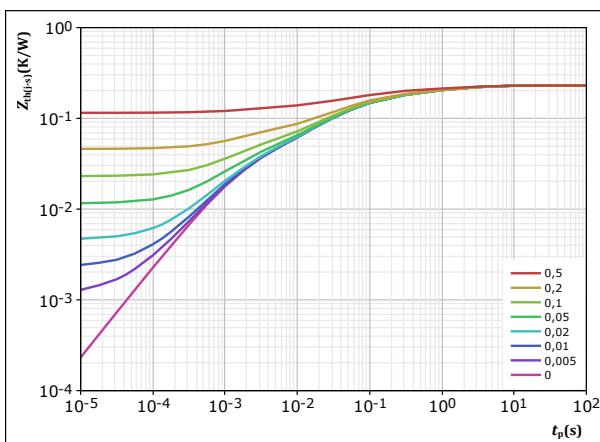
T_F :
— 25 °C
— 125 °C
— 150 °C

figure 16.

Transient thermal impedance as a function of pulse width

$$Z_{th(j-s)} = f(t_p)$$

FWD



$$D = \frac{t_p / T}{R_{th(j-s)}} = 0,23 \quad \text{K/W}$$

FWD thermal model values

R (K/W)	τ (s)
2,56E-02	2,90E+00
4,35E-02	5,53E-01
9,09E-02	6,81E-02
4,34E-02	1,43E-02
2,66E-02	1,41E-03



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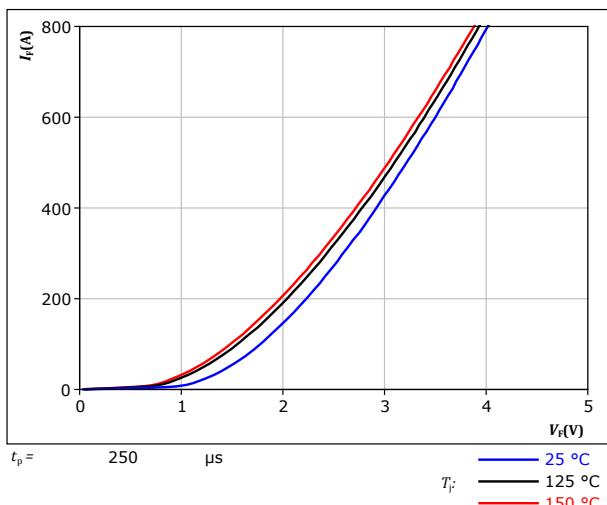
Boost Sw. Inv. Diode Characteristics

figure 17.

Typical forward characteristics

$$I_F = f(V_F)$$

FWD



$$t_p = 250 \mu\text{s}$$

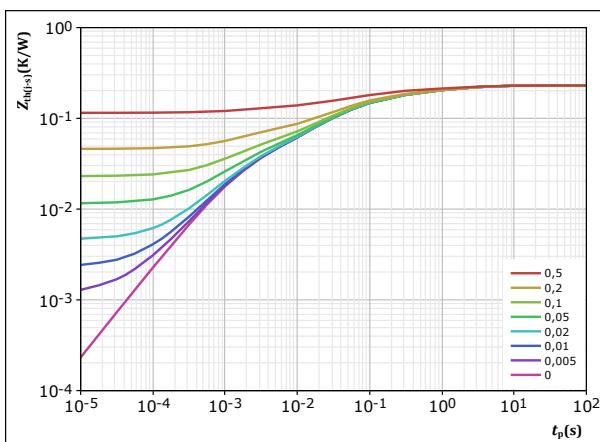
$$T_F: \begin{cases} 25^\circ\text{C} \\ 125^\circ\text{C} \\ 150^\circ\text{C} \end{cases}$$

figure 18.

Transient thermal impedance as a function of pulse width

$$Z_{\text{th}(t_p)} = f(t_p)$$

FWD



$$D = \frac{t_p / T}{R_{\text{th}}(t_p)} = 0,23 \quad \text{K/W}$$

FWD thermal model values

R (K/W)	τ (s)
2,56E-02	2,90E+00
4,35E-02	5,53E-01
9,09E-02	6,81E-02
4,34E-02	1,43E-02
2,66E-02	1,41E-03



Vincotech

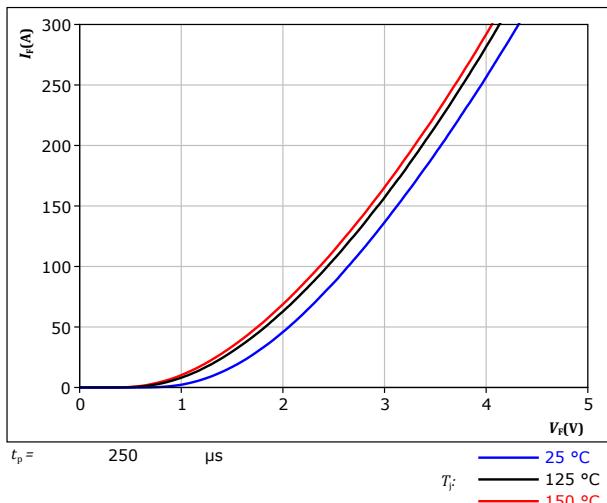
B0-SL10NIB600S701-PA29F48Z
B0-SL10NIC600S701-PA39F48Z
 datasheet

Boost Sw. Protection Diode Characteristics

figure 19.

Typical forward characteristics

$$I_F = f(V_F)$$

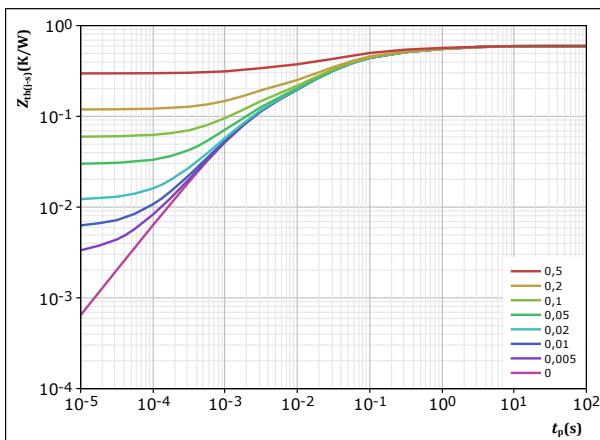


FWD

figure 20.

Transient thermal impedance as a function of pulse width

$$Z_{th(j-s)} = f(t_p)$$



FWD

$$D = \frac{t_p / T}{0,594} \quad K/W$$

FWD thermal model values

R (K/W)	τ (s)
5,02E-02	2,46E+00
7,95E-02	4,43E-01
2,28E-01	5,90E-02
1,50E-01	1,50E-02
8,75E-02	1,73E-03



Vincotech

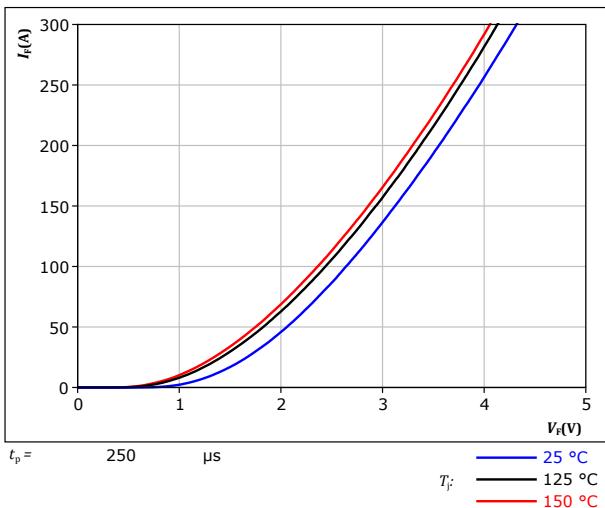
B0-SL10NIB600S701-PA29F48Z
B0-SL10NIC600S701-PA39F48Z
 datasheet

Boost D. Protection Diode Characteristics

figure 21.

Typical forward characteristics

$$I_F = f(V_F)$$

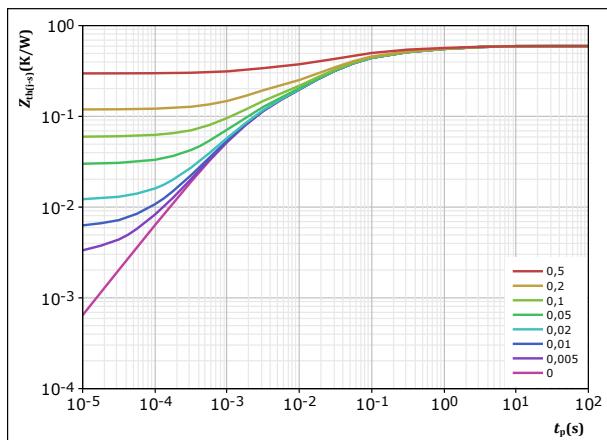


FWD

figure 22.

Transient thermal impedance as a function of pulse width

$$Z_{th(j-s)} = f(t_p)$$



FWD

$$D = \frac{t_p / T}{0,594} \quad K/W$$

FWD thermal model values

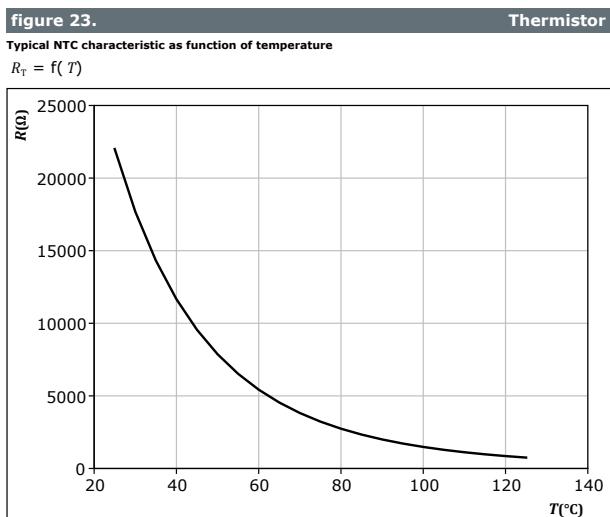
$R (K/W)$	$\tau (s)$
5,02E-02	2,46E+00
7,95E-02	4,43E-01
2,28E-01	5,90E-02
1,50E-01	1,50E-02
8,75E-02	1,73E-03



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datasheet

Thermistor Characteristics





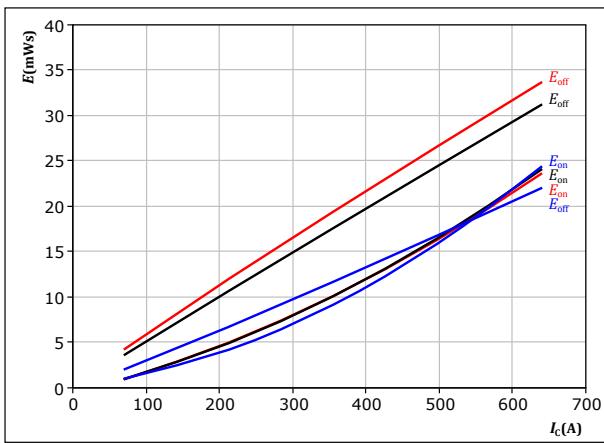
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B0-SL10NIC600S701-PA39F48Z**
datasheet

Buck Switching Characteristics

figure 24.

Typical switching energy losses as a function of collector current
 $E = f(I_c)$

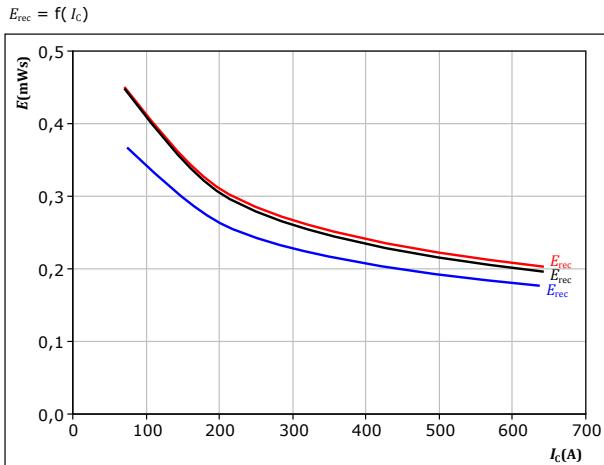


With an inductive load at

$V_{CE} =$	600	V	$T_f:$	25 °C
$V_{GE} =$	±15	V		125 °C
$R_{gon} =$	2	Ω		150 °C
$R_{goff} =$	4	Ω		

figure 26.

Typical reverse recovered energy loss as a function of collector current
 $E_{rec} = f(I_c)$

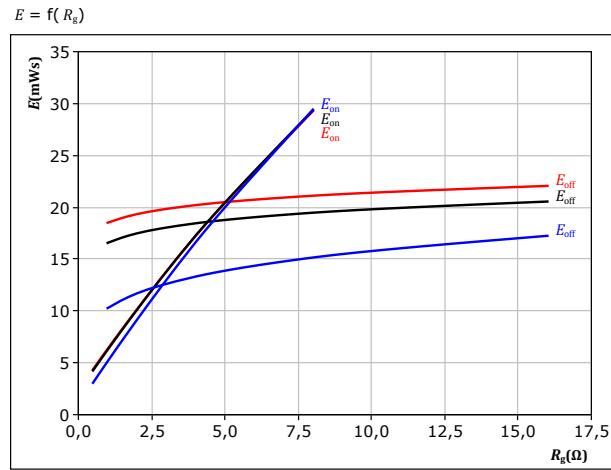


With an inductive load at

$V_{CE} =$	600	V	$T_f:$	25 °C
$V_{GE} =$	±15	V		125 °C
$R_{gon} =$	2	Ω		150 °C
$I_c =$	355	A		

figure 25.

Typical switching energy losses as a function of IGBT turn on gate resistor
 $E = f(R_g)$

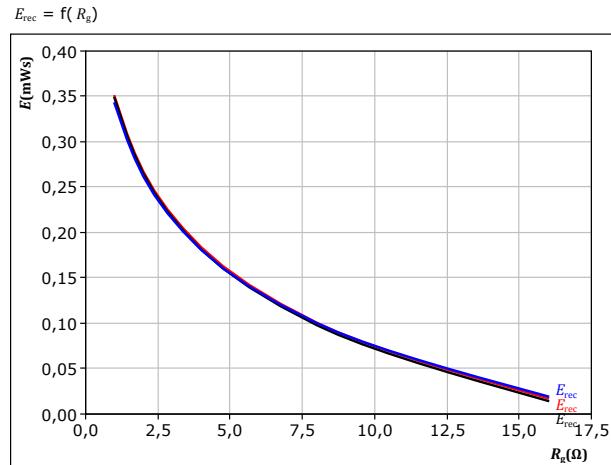


With an inductive load at

$V_{CE} =$	600	V	$T_f:$	25 °C
$V_{GE} =$	±15	V		125 °C
$I_c =$	355	A		150 °C

figure 27.

Typical reverse recovered energy loss as a function of IGBT turn on gate resistor
 $E_{rec} = f(R_g)$



With an inductive load at

$V_{CE} =$	600	V	$T_f:$	25 °C
$V_{GE} =$	±15	V		125 °C
$I_c =$	355	A		150 °C



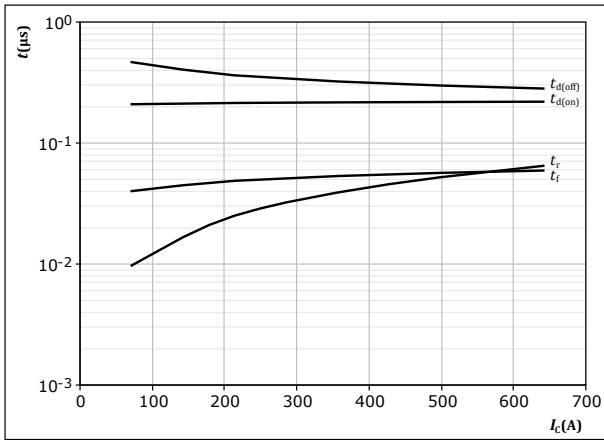
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B0-SL10NIC600S701-PA39F48Z**
datasheet

Buck Switching Characteristics

figure 28.

Typical switching times as a function of collector current
 $t = f(I_C)$



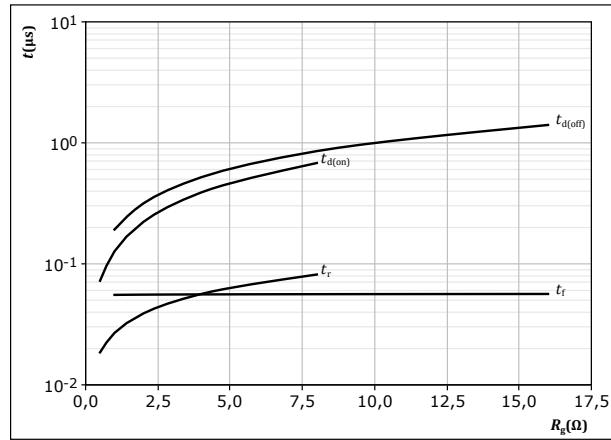
With an inductive load at

$T_j = 150 \text{ } ^\circ\text{C}$
 $V_{CE} = 600 \text{ V}$
 $V_{GE} = \pm 15 \text{ V}$
 $R_{gon} = 2 \Omega$
 $R_{goff} = 4 \Omega$

IGBT

figure 29.

Typical switching times as a function of IGBT turn on gate resistor
 $t = f(R_g)$



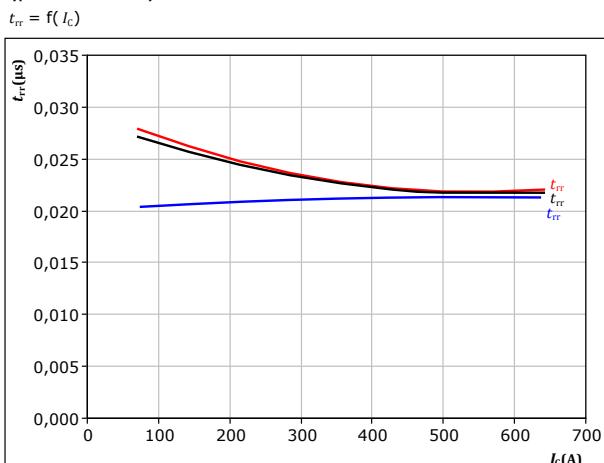
With an inductive load at

$T_j = 150 \text{ } ^\circ\text{C}$
 $V_{CE} = 600 \text{ V}$
 $V_{GE} = \pm 15 \text{ V}$
 $I_C = 355 \text{ A}$

IGBT

figure 30.

Typical reverse recovery time as a function of collector current
 $t_{rr} = f(I_C)$



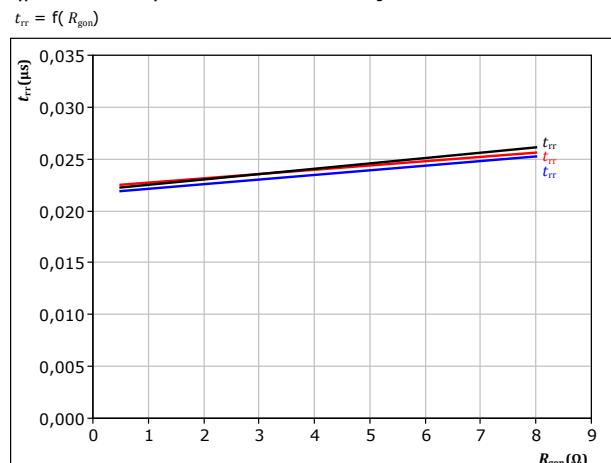
With an inductive load at

$V_{CE} = 600 \text{ V}$
 $V_{GE} = \pm 15 \text{ V}$
 $R_{gon} = 2 \Omega$

FWD

figure 31.

Typical reverse recovery time as a function of IGBT turn on gate resistor
 $t_{rr} = f(R_{gon})$



With an inductive load at

$V_{CE} = 600 \text{ V}$
 $V_{GE} = \pm 15 \text{ V}$
 $I_C = 355 \text{ A}$

FWD



Vincotech

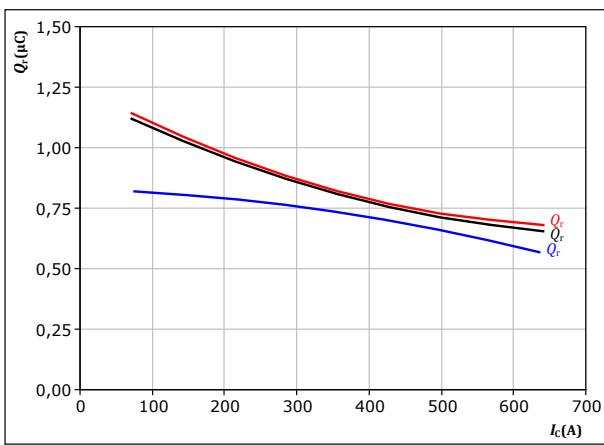
B0-SL10NIB600S701-PA29F48Z
B0-SL10NIC600S701-PA39F48Z
 datasheet

Buck Switching Characteristics

figure 32.

Typical recovered charge as a function of collector current

$$Q_r = f(I_c)$$



With an inductive load at

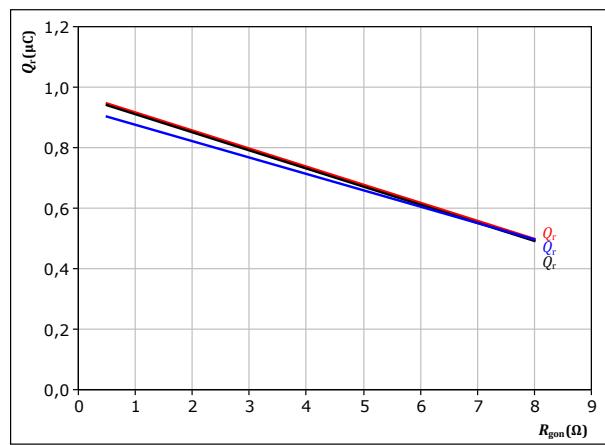
$$\begin{aligned} V_{CE} &= 600 \quad \text{V} & T_f &= 125 \text{ }^{\circ}\text{C} \\ V_{GE} &= \pm 15 \quad \text{V} & & \\ R_{gon} &= 2 \quad \Omega & & \end{aligned}$$

FWD

figure 33.

Typical recovered charge as a function of IGBT turn on gate resistor

$$Q_r = f(R_{gon})$$



With an inductive load at

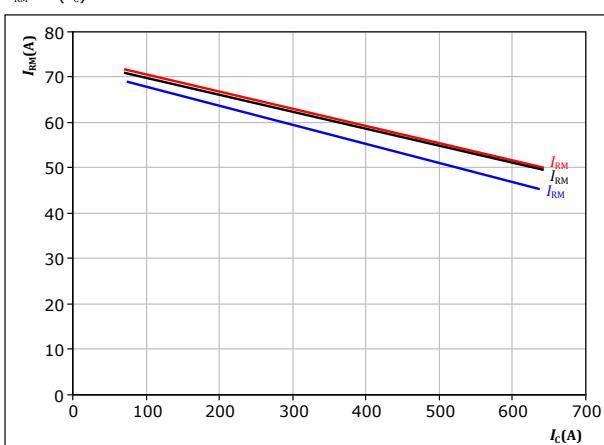
$$\begin{aligned} V_{CE} &= 600 \quad \text{V} & T_f &= 125 \text{ }^{\circ}\text{C} \\ V_{GE} &= \pm 15 \quad \text{V} & & \\ I_c &= 355 \quad \text{A} & & \end{aligned}$$

FWD

figure 34.

Typical peak reverse recovery current as a function of collector current

$$I_{RM} = f(I_c)$$



With an inductive load at

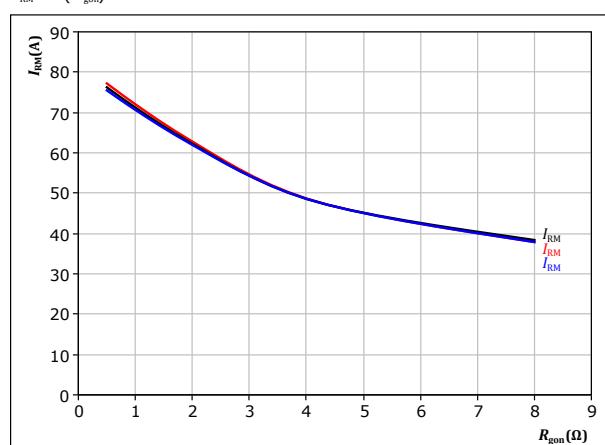
$$\begin{aligned} V_{CE} &= 600 \quad \text{V} & T_f &= 125 \text{ }^{\circ}\text{C} \\ V_{GE} &= \pm 15 \quad \text{V} & & \\ R_{gon} &= 2 \quad \Omega & & \end{aligned}$$

FWD

figure 35.

Typical peak reverse recovery current as a function of IGBT turn on gate resistor

$$I_{RM} = f(R_{gon})$$



With an inductive load at

$$\begin{aligned} V_{CE} &= 600 \quad \text{V} & T_f &= 125 \text{ }^{\circ}\text{C} \\ V_{GE} &= \pm 15 \quad \text{V} & & \\ I_c &= 355 \quad \text{A} & & \end{aligned}$$

FWD



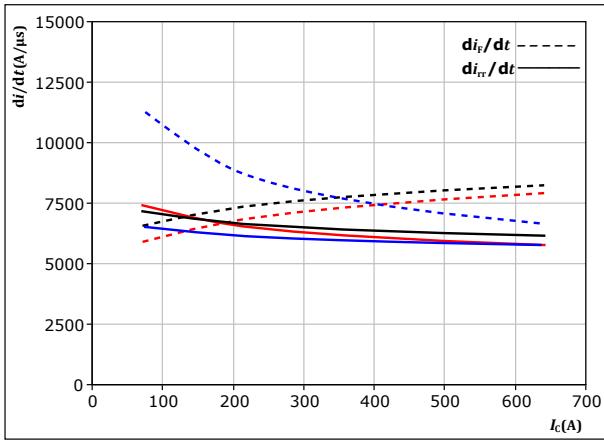
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datasheet

Buck Switching Characteristics

figure 36. FWD

Typical rate of fall of forward and reverse recovery current as a function of collector current
 $di_f/dt, di_{rr}/dt = f(I_c)$



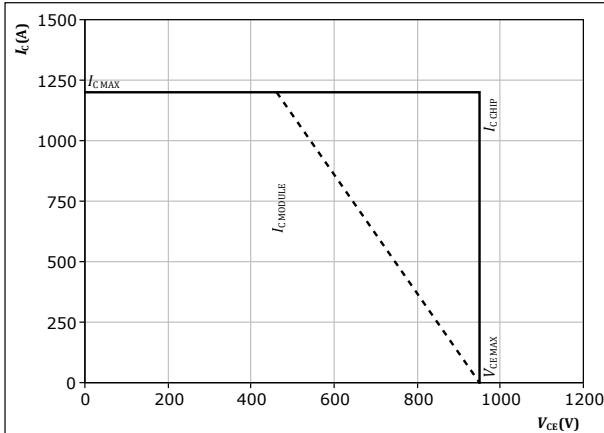
With an inductive load at

$V_{CE} =$	600	V	$T_j =$	25 °C
$V_{GE} =$	± 15	V		125 °C
$R_{gon} =$	2	Ω		150 °C

figure 38. IGBT

Reverse bias safe operating area

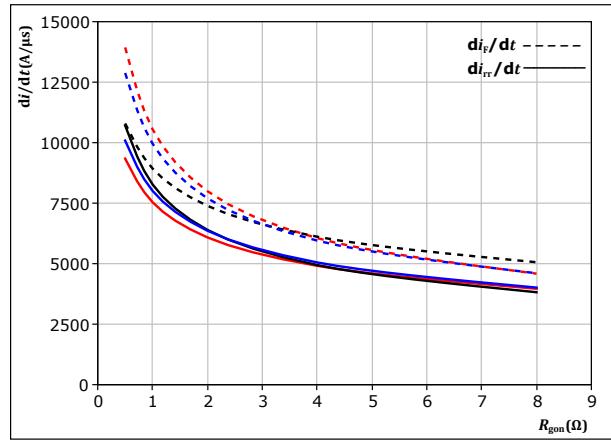
$I_c = f(V_{CE})$



At $T_j = 150$ °C
 $R_{gon} = 2$ Ω
 $R_{goff} = 4$ Ω

figure 37. FWD

Typical rate of fall of forward and reverse recovery current as a function of turn on gate resistor
 $di_f/dt, di_{rr}/dt = f(R_{gon})$



With an inductive load at

$V_{CE} =$	600	V	$T_j =$	25 °C
$V_{GE} =$	± 15	V		125 °C
$I_c =$	355	A		150 °C



Vincotech

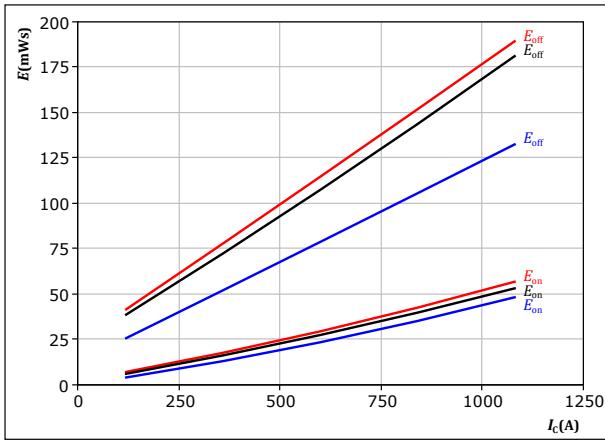
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B0-SL10NIC600S701-PA39F48Z
 datasheet

Boost Switching Characteristics

figure 39.

Typical switching energy losses as a function of collector current

$$E = f(I_c)$$



With an inductive load at

$$V_{CE} = 600 \text{ V}$$

$$V_{GE} = \pm 15 \text{ V}$$

$$R_{gon} = 2 \Omega$$

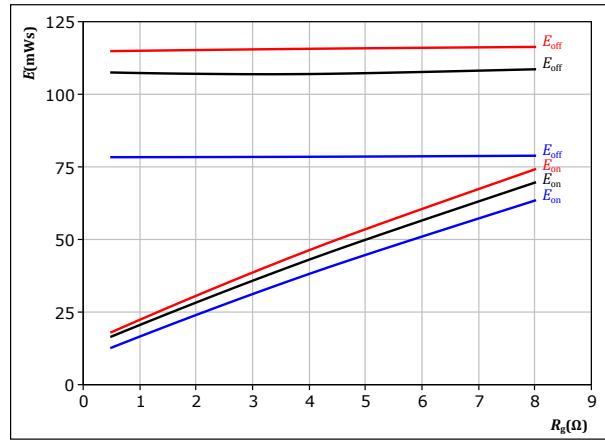
$$R_{goff} = 2 \Omega$$

IGBT

figure 40.

Typical switching energy losses as a function of IGBT turn on gate resistor

$$E = f(R_g)$$



With an inductive load at

$$V_{CE} = 600 \text{ V}$$

$$V_{GE} = \pm 15 \text{ V}$$

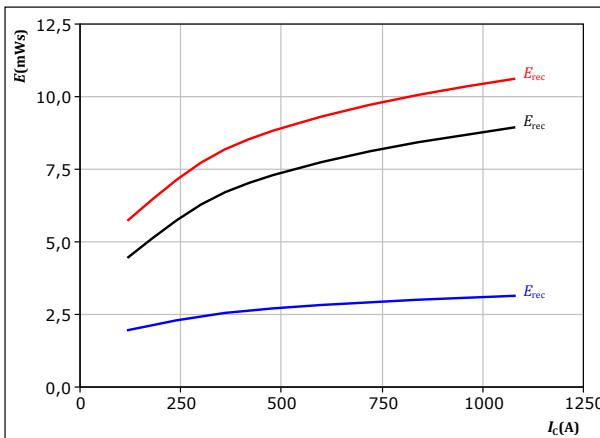
$$I_c = 600 \text{ A}$$

IGBT

figure 41.

Typical reverse recovered energy loss as a function of collector current

$$E_{rec} = f(I_c)$$



With an inductive load at

$$V_{CE} = 600 \text{ V}$$

$$V_{GE} = \pm 15 \text{ V}$$

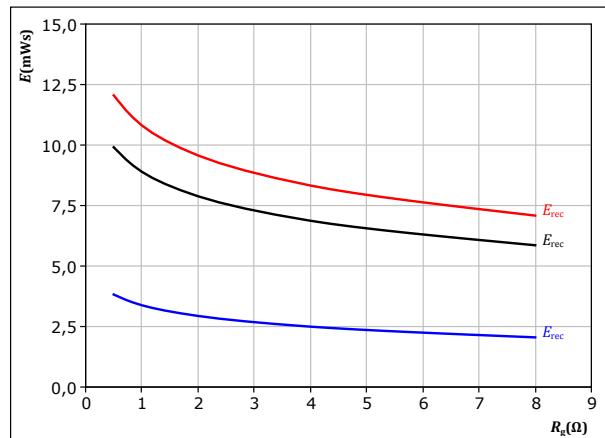
$$R_{gon} = 2 \Omega$$

FWD

figure 42.

Typical reverse recovered energy loss as a function of IGBT turn on gate resistor

$$E_{rec} = f(R_g)$$



With an inductive load at

$$V_{CE} = 600 \text{ V}$$

$$V_{GE} = \pm 15 \text{ V}$$

$$I_c = 600 \text{ A}$$

FWD



Vincotech

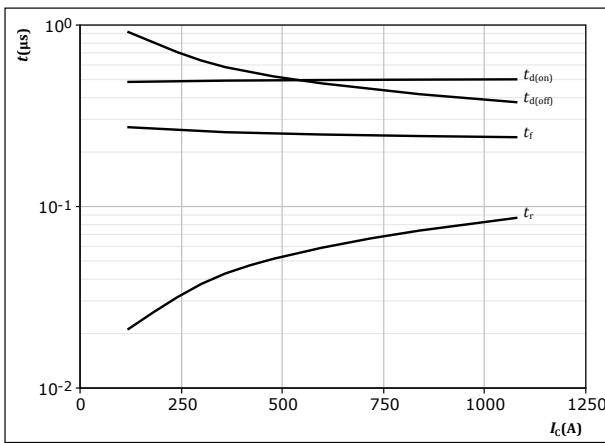
B0-SL10NIB600S701-PA29F48Z
B0-SL10NIC600S701-PA39F48Z
 datasheet

Boost Switching Characteristics

figure 43.

IGBT

Typical switching times as a function of collector current
 $t = f(I_C)$



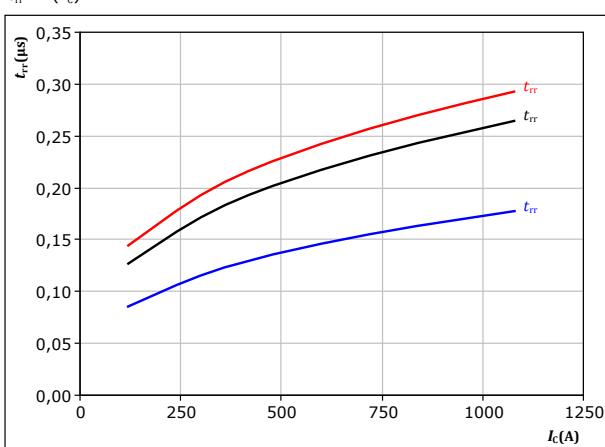
With an inductive load at

$T_j = 150^\circ\text{C}$
 $V_{CE} = 600 \text{ V}$
 $V_{GE} = \pm 15 \text{ V}$
 $R_{gon} = 2 \Omega$
 $R_{goff} = 2 \Omega$

figure 45.

FWD

Typical reverse recovery time as a function of collector current
 $t_{rr} = f(I_C)$



With an inductive load at

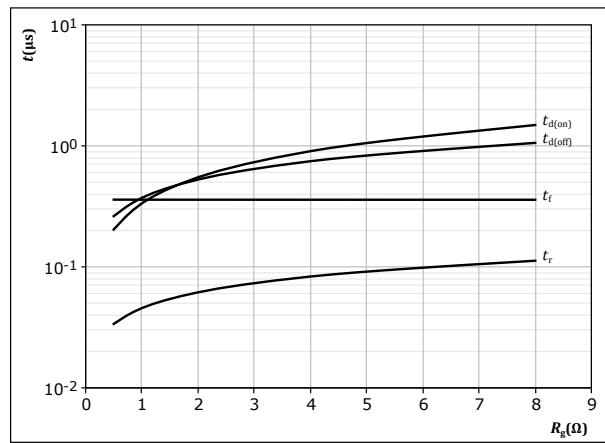
$V_{CE} = 600 \text{ V}$
 $V_{GE} = \pm 15 \text{ V}$
 $R_{gon} = 2 \Omega$

$T_j:$ — 25 °C — 125 °C — 150 °C

figure 44.

IGBT

Typical switching times as a function of IGBT turn on gate resistor
 $t = f(R_g)$



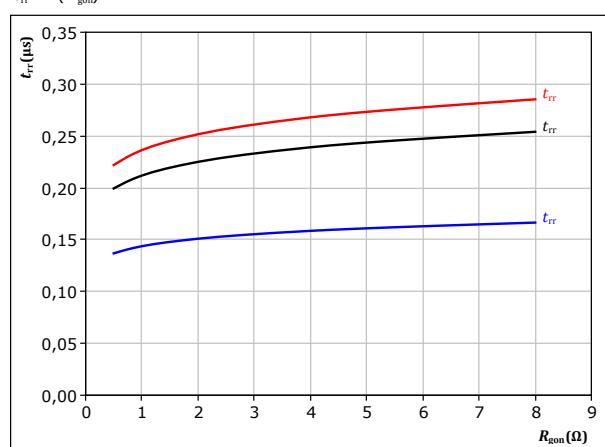
With an inductive load at

$T_j = 150^\circ\text{C}$
 $V_{CE} = 600 \text{ V}$
 $V_{GE} = \pm 15 \text{ V}$
 $I_C = 600 \text{ A}$

figure 46.

FWD

Typical reverse recovery time as a function of IGBT turn on gate resistor
 $t_{rr} = f(R_{gon})$



With an inductive load at

$V_{CE} = 600 \text{ V}$
 $V_{GE} = \pm 15 \text{ V}$
 $I_C = 600 \text{ A}$

$T_j:$ — 25 °C — 125 °C — 150 °C



Vincotech

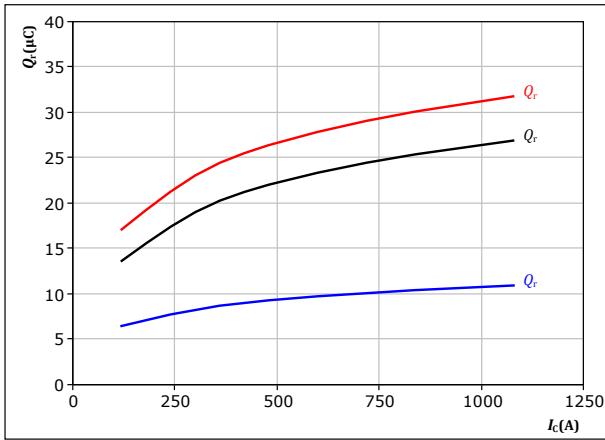
B0-SL10NIB600S701-PA29F48Z
B0-SL10NIC600S701-PA39F48Z
 datasheet

Boost Switching Characteristics

figure 47.

Typical recovered charge as a function of collector current

$$Q_r = f(I_c)$$



With an inductive load at

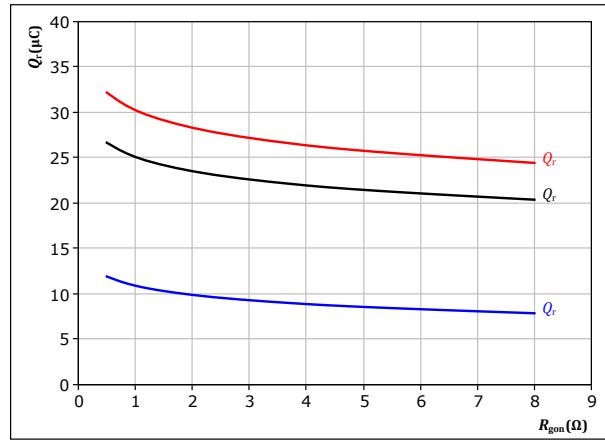
$$\begin{aligned} V_{CE} &= 600 \text{ V} \\ V_{GE} &= \pm 15 \text{ V} \\ R_{gon} &= 2 \Omega \end{aligned}$$

FWD

figure 48.

Typical recovered charge as a function of IGBT turn on gate resistor

$$Q_r = f(R_{gon})$$



With an inductive load at

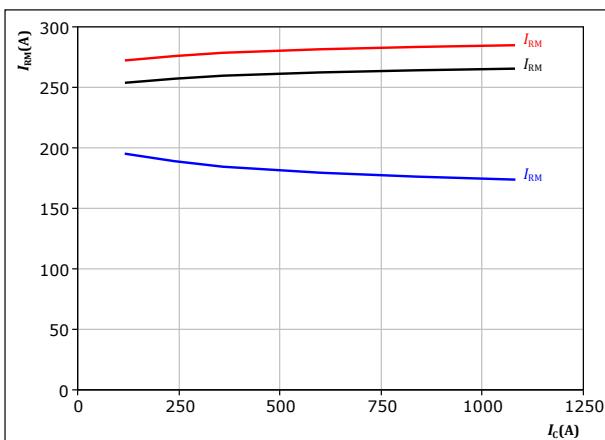
$$\begin{aligned} V_{CE} &= 600 \text{ V} \\ V_{GE} &= \pm 15 \text{ V} \\ I_c &= 600 \text{ A} \end{aligned}$$

FWD

figure 49.

Typical peak reverse recovery current as a function of collector current

$$I_{RM} = f(I_c)$$



With an inductive load at

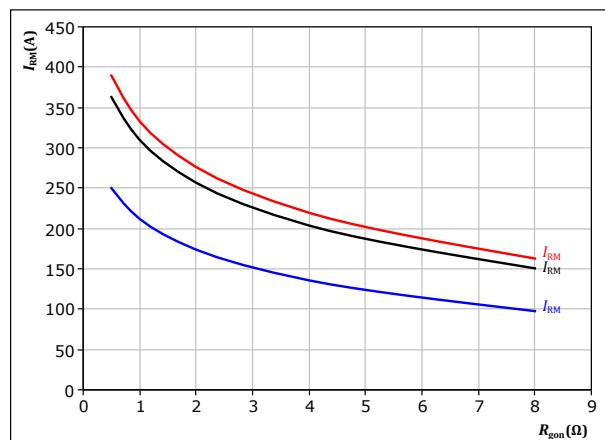
$$\begin{aligned} V_{CE} &= 600 \text{ V} \\ V_{GE} &= \pm 15 \text{ V} \\ R_{gon} &= 2 \Omega \end{aligned}$$

FWD

figure 50.

Typical peak reverse recovery current as a function of IGBT turn on gate resistor

$$I_{RM} = f(R_{gon})$$



With an inductive load at

$$\begin{aligned} V_{CE} &= 600 \text{ V} \\ V_{GE} &= \pm 15 \text{ V} \\ I_c &= 600 \text{ A} \end{aligned}$$

FWD



Vincotech

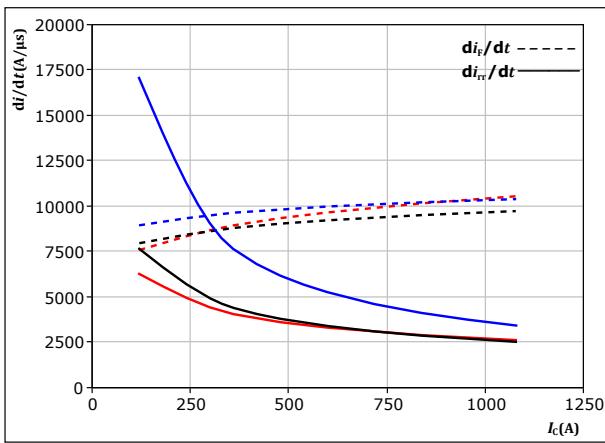
**B0-SL10NIB600S701-PA29F48Z
B0-SL10NIC600S701-PA39F48Z**
datasheet

Boost Switching Characteristics

figure 51. FWD

Typical rate of fall of forward and reverse recovery current as a function of collector current

$di_f/dt, di_{rr}/dt = f(I_c)$



With an inductive load at

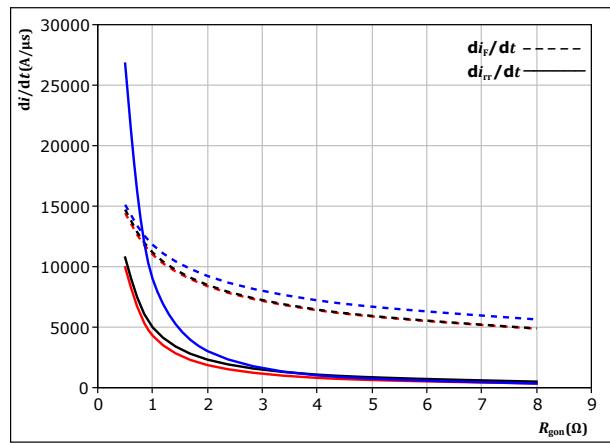
$V_{CE} = 600$ V
 $V_{GE} = \pm 15$ V
 $R_{gon} = 2$ Ω

T_j : 25 °C (blue line)
125 °C (black line)
150 °C (red line)

figure 52. FWD

Typical rate of fall of forward and reverse recovery current as a function of turn on gate resistor

$di_f/dt, di_{rr}/dt = f(R_{gon})$



With an inductive load at

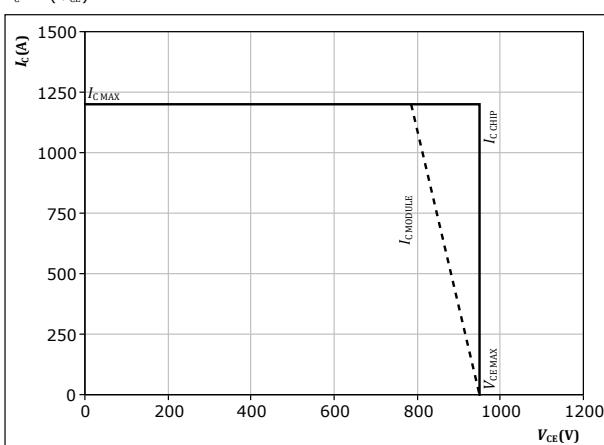
$V_{CE} = 600$ V
 $V_{GE} = \pm 15$ V
 $I_c = 600$ A

T_j : 25 °C (blue line)
125 °C (black line)
150 °C (red line)

figure 53. IGBT

Reverse bias safe operating area

$I_c = f(V_{CE})$



At $T_j = 150$ °C
 $R_{gon} = 2$ Ω
 $R_{goff} = 2$ Ω



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Switching Definitions

figure 54. IGBT

Turn-off Switching Waveforms & definition of t_{doff} , t_{Eoff} (t_{Eoff} = integrating time for E_{off})

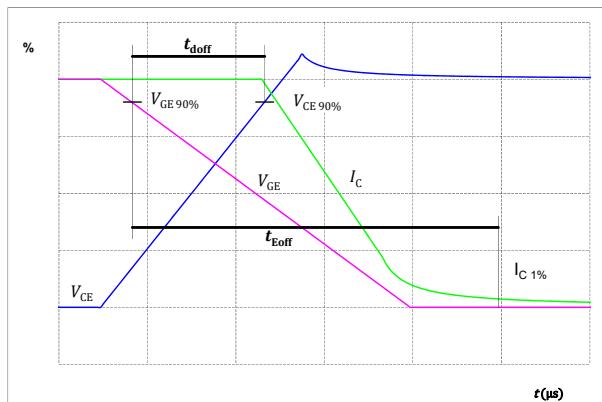


figure 56. IGBT

Turn-off Switching Waveforms & definition of t_f

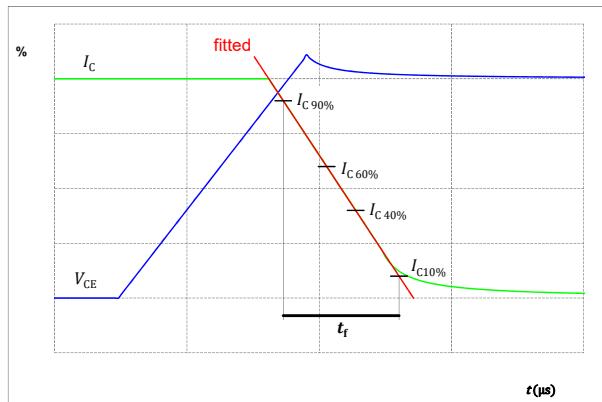


figure 55. IGBT

Turn-on Switching Waveforms & definition of t_{don} , t_{Eon} (t_{Eon} = integrating time for E_{on})

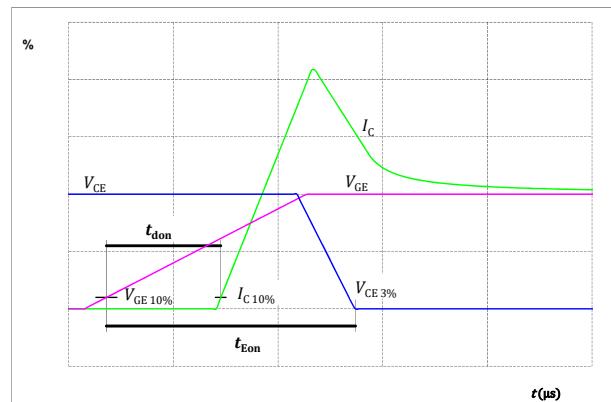
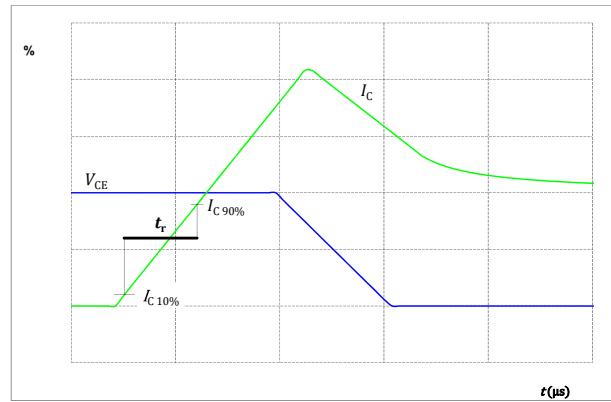


figure 57. IGBT

Turn-on Switching Waveforms & definition of t_r





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Switching Definitions

figure 58.

Turn-off Switching Waveforms & definition of t_{tr}

FWD

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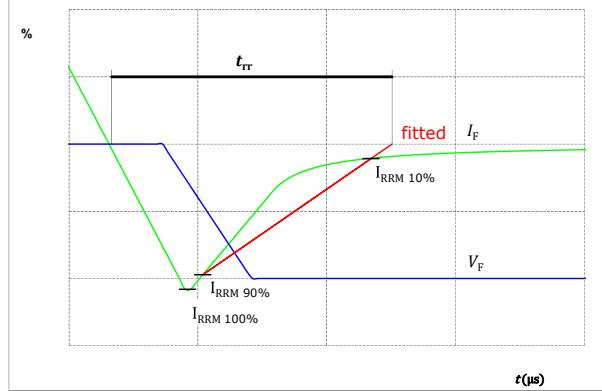
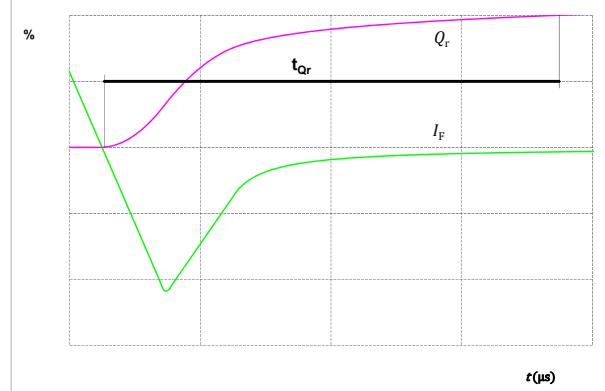


figure 59.

Turn-on Switching Waveforms & definition of t_{qr} (t_{qr} = integrating time for Q_r)

FWD

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<table border="1"> <thead> <tr> <th>Pin</th><th>X</th><th>Y</th><th>Function</th></tr> </thead> <tbody> <tr><td>1</td><td>6,2</td><td>49,4</td><td>Therm1</td></tr> <tr><td>2</td><td>0</td><td>49,4</td><td>Therm2</td></tr> <tr><td>3</td><td>0,3</td><td>5,4</td><td>DC+</td></tr> <tr><td>4</td><td>3</td><td>5,4</td><td>DC+</td></tr> <tr><td>5</td><td>5,7</td><td>5,4</td><td>DC+</td></tr> <tr><td>6</td><td>8,4</td><td>5,4</td><td>DC+</td></tr> <tr><td>7</td><td>0,3</td><td>2,7</td><td>DC+</td></tr> <tr><td>8</td><td>3</td><td>2,7</td><td>DC+</td></tr> <tr><td>9</td><td>5,7</td><td>2,7</td><td>DC+</td></tr> <tr><td>10</td><td>0,3</td><td>0</td><td>DC+</td></tr> <tr><td>11</td><td>3</td><td>0</td><td>DC+</td></tr> <tr><td>12</td><td>5,7</td><td>0</td><td>DC+</td></tr> <tr><td>13</td><td>14,5</td><td>0</td><td>GND</td></tr> <tr><td>14</td><td>17,2</td><td>0</td><td>GND</td></tr> <tr><td>15</td><td>19,9</td><td>0</td><td>GND</td></tr> <tr><td>16</td><td>22,6</td><td>0</td><td>GND</td></tr> <tr><td>17</td><td>31,8</td><td>0</td><td>GND</td></tr> <tr><td>18</td><td>34,5</td><td>0</td><td>GND</td></tr> <tr><td>19</td><td>37,2</td><td>0</td><td>GND</td></tr> <tr><td>20</td><td>39,9</td><td>0</td><td>GND</td></tr> <tr><td>21</td><td>48,7</td><td>0</td><td>DC-</td></tr> <tr><td>22</td><td>51,4</td><td>0</td><td>DC-</td></tr> <tr><td>23</td><td>51,4</td><td>2,7</td><td>DC-</td></tr> <tr><td>24</td><td>51,4</td><td>5,4</td><td>DC-</td></tr> <tr><td>25</td><td>51,4</td><td>8,1</td><td>DC-</td></tr> <tr><td>26</td><td>51,4</td><td>10,8</td><td>DC-</td></tr> <tr><td>27</td><td>51,4</td><td>13,5</td><td>DC-</td></tr> <tr><td>28</td><td>40,6</td><td>43,7</td><td>Ph</td></tr> <tr><td>29</td><td>37,9</td><td>43,7</td><td>Ph</td></tr> <tr><td>30</td><td>35,2</td><td>43,7</td><td>Ph</td></tr> <tr><td>31</td><td>40,6</td><td>46,4</td><td>Ph</td></tr> <tr><td>32</td><td>37,9</td><td>46,4</td><td>Ph</td></tr> <tr><td>33</td><td>35,2</td><td>46,4</td><td>Ph</td></tr> <tr><td>34</td><td>40,6</td><td>49,1</td><td>Ph</td></tr> <tr><td>35</td><td>37,9</td><td>49,1</td><td>Ph</td></tr> <tr><td>36</td><td>35,2</td><td>49,1</td><td>Ph</td></tr> <tr><td>37</td><td>32,5</td><td>49,1</td><td>Ph</td></tr> <tr><td>38</td><td>12,4</td><td>26,95</td><td>G11</td></tr> <tr><td>39</td><td>16,1</td><td>26,95</td><td>S11</td></tr> <tr><td>40</td><td>32,95</td><td>27,3</td><td>G13</td></tr> <tr><td>41</td><td>36,65</td><td>27,3</td><td>S13</td></tr> <tr><td>42</td><td>21,05</td><td>49,1</td><td>TM1</td></tr> <tr><td>43</td><td>51,4</td><td>33,6</td><td>TM2</td></tr> </tbody> </table>	Pin	X	Y	Function	1	6,2	49,4	Therm1	2	0	49,4	Therm2	3	0,3	5,4	DC+	4	3	5,4	DC+	5	5,7	5,4	DC+	6	8,4	5,4	DC+	7	0,3	2,7	DC+	8	3	2,7	DC+	9	5,7	2,7	DC+	10	0,3	0	DC+	11	3	0	DC+	12	5,7	0	DC+	13	14,5	0	GND	14	17,2	0	GND	15	19,9	0	GND	16	22,6	0	GND	17	31,8	0	GND	18	34,5	0	GND	19	37,2	0	GND	20	39,9	0	GND	21	48,7	0	DC-	22	51,4	0	DC-	23	51,4	2,7	DC-	24	51,4	5,4	DC-	25	51,4	8,1	DC-	26	51,4	10,8	DC-	27	51,4	13,5	DC-	28	40,6	43,7	Ph	29	37,9	43,7	Ph	30	35,2	43,7	Ph	31	40,6	46,4	Ph	32	37,9	46,4	Ph	33	35,2	46,4	Ph	34	40,6	49,1	Ph	35	37,9	49,1	Ph	36	35,2	49,1	Ph	37	32,5	49,1	Ph	38	12,4	26,95	G11	39	16,1	26,95	S11	40	32,95	27,3	G13	41	36,65	27,3	S13	42	21,05	49,1	TM1	43	51,4	33,6	TM2	 <small>Tolerances are shown at the end of the drawing. Dimension of coordinate axis is only valid without tolerance.</small>					
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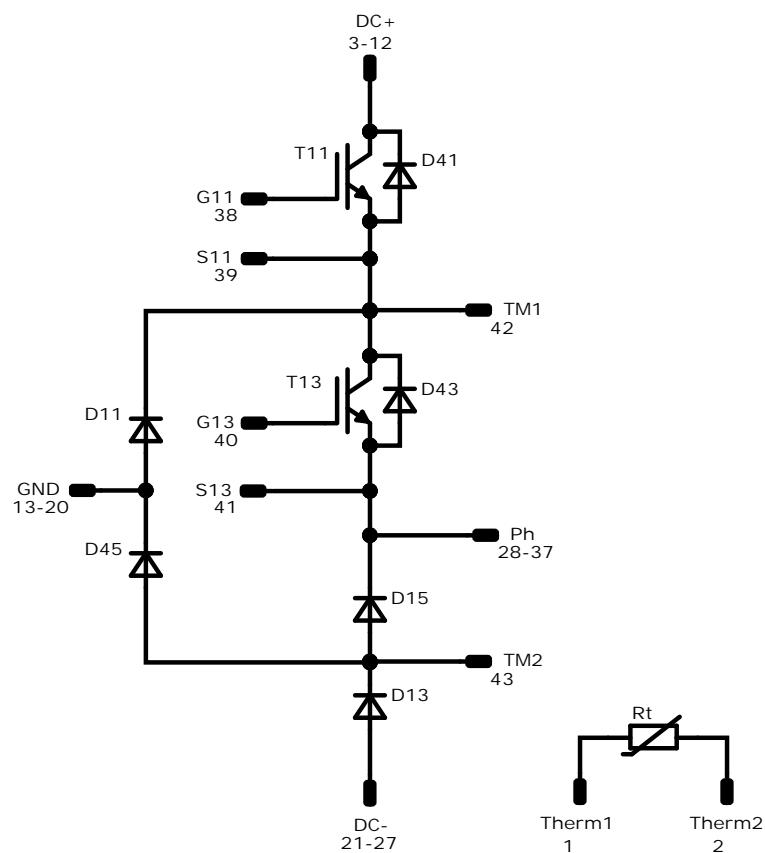


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datasheet

B0-SL10NIB600S701-PA29F48Z

Pinout



Identification

ID	Component	Voltage	Current	Function	Comment
T11	IGBT	950 V	600 A	Buck Switch	
D11	FWD	1200 V	160 A	Buck Diode	
D41	FWD	950 V	100 A	Buck Sw. Protection Diode	
T13	IGBT	950 V	600 A	Boost Switch	
D13	FWD	950 V	300 A	Boost Diode	
D15	FWD	950 V	300 A	Boost Sw. Inv. Diode	
D43	FWD	950 V	100 A	Boost Sw. Protection Diode	
D45	FWD	950 V	100 A	Boost D. Protection Diode	
Rt	Thermistor			Thermistor	



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B0-SL10NIC600S701-PA39F48Z
 datasheet

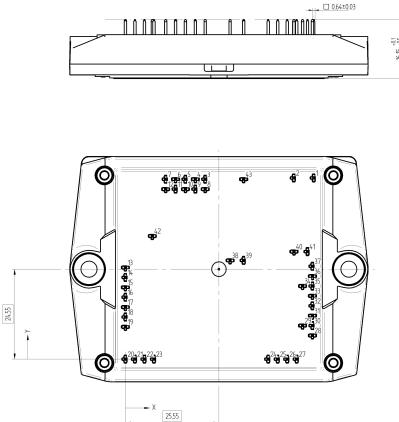
Ordering Code	
Version	Ordering Code
Without thermal paste	B0-SL10NIC600S701-PA39F48Z
With thermal paste (5,2 W/mK, PTM6000HV)	B0-SL10NIC600S701-PA39F48Z-/7/

Marking						
Text	Name	Date code	UL & VIN	Lot	Serial	
	NN-NNNNNNNNNNNNNN TTTTTTVVVWY YJ VIN LLLL SSSS	WWYY	UL VIN	LLLLL	SSSS	
Datamatrix	Type&Ver TTTTTTVV	Lot number LLLLL	Serial SSSS	Date code WWYY		

B0-SL10NIC600S701-PA39F48Z

Outline

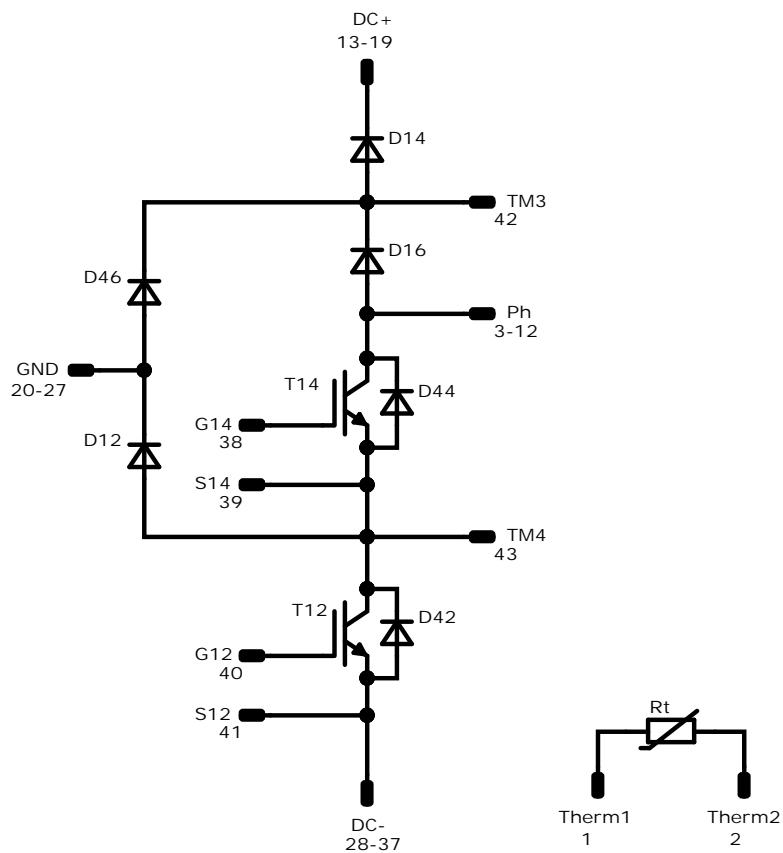
Pin table [mm]			
Pin	X	Y	Function
1	51,45	49,45	Therm1
2	46	49,45	Therm2
3	21,8	49,1	Ph
4	19,1	49,1	Ph
5	16,4	49,1	Ph
6	13,7	49,1	Ph
7	11	49,1	Ph
8	21,8	46,4	Ph
9	19,1	46,4	Ph
10	16,4	46,4	Ph
11	13,7	46,4	Ph
12	11	46,4	Ph
13	0	25	DC+
14	0	22,3	DC+
15	0	19,6	DC+
16	0	16,9	DC+
17	0	14,2	DC+
18	0	11,5	DC+
19	0	8,8	DC+
20	0	0	GND
21	2,6	0	GND
22	5,2	0	GND
23	7,8	0	GND
24	39	0	GND
25	41,6	0	GND
26	44,2	0	GND
27	46,8	0	GND
28	51,1	6,45	DC-
29	48,4	9,15	DC-
30	51,1	9,15	DC-
31	51,1	11,85	DC-
32	51,1	14,55	DC-
33	51,1	17,25	DC-
34	48,4	19,95	DC-
35	51,1	19,95	DC-
36	51,1	22,65	DC-
37	51,1	25,35	DC-
38	28,6	26,95	G14
39	32,3	26,95	S14
40	46,05	29,35	G12
41	49,75	29,35	S12
42	7,35	33,6	TM3
43	32,3	49,1	TM4



Technical drawing specifies sizes of the outline of part.
Dimension of coordinate axis is only valid without tolerance.

BO-SL10NIC600S701-PA39F48Z

Pinout



Identification

ID	Component	Voltage	Current	Function	Comment
T12	IGBT	950 V	600 A	Buck Switch	
D12	FWD	1200 V	160 A	Buck Diode	
D42	FWD	950 V	100 A	Buck Sw. Protection Diode	
T14	IGBT	950 V	600 A	Boost Switch	
D14	FWD	950 V	300 A	Boost Diode	
D16	FWD	950 V	300 A	Boost Sw. Inv. Diode	
D44	FWD	950 V	100 A	Boost Sw. Protection Diode	
D46	FWD	950 V	100 A	Boost D. Protection Diode	
Rt	Thermistor			Thermistor	



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B0-SL10NIB600S701-PA29F48Z**B0-SL10NIC600S701-PA39F48Z**

datasheet

Packaging instruction

Standard packaging quantity (SPQ) 45	>SPQ	Standard	<SPQ	Sample
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Handling instruction

Handling instructions for flow S3 packages see vincotech.com website.

Package data

Package data for flow S3 packages see vincotech.com website.

Vincotech thermistor reference

See Vincotech thermistor reference table at vincotech.com website.

UL recognition and file number

This device is certified according to UL 1557 standard, UL file number E192116. For more information see vincotech.com website.



Document No.:	Date:	Modification:	Pages
B0-SL10NIx600S701-PAx9F48Z-D3-14	15 Dec. 2022	Frame, Pin table and Pinout modification	

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2. A critical component is any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.